DEI P/N:	OCXO3311C	
Nominal Freq.:	<u>8 ~100 MHz</u>	
GSL P/N:		
Revision:	01	
Date:	2015.04.01	

Approved / Date	Checked / Date	Prepared / Date		
Greg/2015.04	David/2015.04.01	Catherine/2015.04.01		

Customer:

Customer P/N: <u>N/A</u>

REVISION HISTORY (OCXO3311C)

Revision #	Revised Page(s)	Revision Content	Date	Ref Number	Revision Requested by	Reviser
1		Initial Release	04/01/15		Lee	Catherine

Features and Benefits

Very small sizes Very low power consumption (to 0.23W at +25 °C) Very high mechanical strength: to up 500G, 1ms shocks Vibration 30G to 2000Hz sine High frequency stability (to +/-10ppb over -40°C to 85°C) Fast warming-up: 60s to 0.1ppm accuracy Operational frequency range: 8 to 100MHz

Description

The OCXO3311C series ovenized oscillator employs a directly heated crystal process which delivers very fast warmup, excellent phase noise and frequency long term stability in a very small industry-standard package.

Typical Applications

Portable Wireless Communications Mobile Test equipment Beacons & Rescue systems Equipment working at severe mechanical factors.

Mechanical Drawing & Pin Connections

Physical dimensions





Drawing No: MD140038-2

Pin	Signal
1	Electrical tuning
2	Reference voltage
4	GND
5	RF Out
8	+V Supply

Unit : mm

Dynamic Engineers, Inc.

Revision: 1

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Specifications

OCXO Specification		Sum	Condition	Value			Unit	Noto
		Sym		Min.	Тур.	Max.	Onit	Note
Frequency Range		Fo		8		100	MHz	
RF Outpu	ut							
	Lood			10			kOhm	
	Load					15	pF	
LCMOS	H-level Voltage	V _H		3.8			V	
	L-level Voltage	VL				0.4	V	
	Duty Cycle			45		55	%	
	Rise/Fall Time					10	ns	For 10MHz optional frequency
Power St	upply							
Voltage		V _{cc}		4.75	5.0	5.25	V	3.3V available
Rowor Co	nsumption	h.	Warm-up state		1.0		W	
Fower Co	Jisumption	Warm-up	Steady state, +25°C		0.23		W	
Warm-up Time			∆f/f₀ = 1e-7 at 25°C, V _{cc} =5V	30	60		s	ref. to frequency after
		ι _{up}	∆f/f₀ = 1e-7 at 25°C, V₀c=3.3V	40	70		s	15 min
Frequenc	cy Control							
			@ V _{cc} = 5V	0		4.2	V	Tuning slope – positive
Control V	oltage Range	V _c	@ V _{cc} = 3.3V	0		2.8	V	(standard option)
Tuning Ra	ange			+/-0.5	+/-1	-	maa	
	- <u>-</u>		@ V _{cc} = 5V	4.1	4.2	4.3	V	
Reference	e Voltage	V _{ref}	@ V _{cc} = 3.3V	2.7	2.8	2.9	V	
Frequence	cy Stability							
vs. Tempe	erature		-30°C to +70°C, ref. 25°C		+/-50		ppb	For more information, please consult sale
vs. Supply Voltage			Ref. V _{cc} typ.		+/-2		ppb	•
vs. Accele	eration		Worst direction			+/-1	ppb/G	
Aging	Per Day		After 30 days of		+/-0.5		ppb	For more information,
Aging	First Year		operation		+/-0.05		ppm	please consult sale
Phase No	oise							
			1Hz		-97		dBc/Hz	Utmost phase noise
			10Hz		-127			
Phase No	bise		100Hz		-152			
			1kHz		-162			level tominz op. neq.
			10kHz		-166			
Environmental								
Operating	Operating Temperature Range -30°C to +70°C							
Storage T	Storage Temperature Range -60°C to +90°C							
Humidity	Itality Non-condensing 95%							
Mechanical Shock Per MiL-STD-202, SUUG hair sine pulse, 11ms (SUUG, 1ms-Special option)								
VIDration	Conditions	Per MIL-S	Per INIL-51 D-202,30G Swept sine 10 to 2000Hz					
Soldering Conditions		Hand solder only – not reflow compatible, 260°C 10s (on pins)						

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